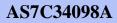
August 2004





$3.3~V~256~K\times 16~CMOS~SRAM$

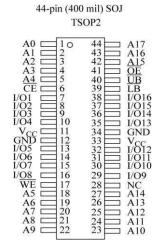
Features

- Pin compatible with AS7C34098
- Industrial and commercial temperature
- Organization: 262,144 words \times 16 bits
- Center power and ground pins
- High speed
 - 10/12/15/20 ns address access time
 - 4/5/6/7 ns output enable access time
- Low power consumption: ACTIVE - 650 mW /max @ 10 ns
- Low power consumption: STANDBY - 28.8 mW /max CMOS
- Individual byte read/write controls

Logic block diagram

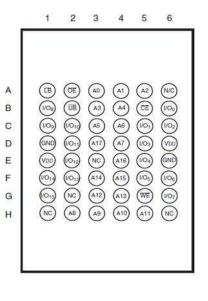
- Easy memory expansion with \overline{CE} , \overline{OE} inputs
- TTL- and CMOS-compatible, three-state I/O
- JEDEC standard packages
- 44-pin SOJ -400-mil
- 44-pin TSOP 2
- 48-pin Mini BGA
- ESD protection ≥ 2000 volts
- Latch-up current $\ge 200 \text{ mA}$

$A0 \rightarrow V_{CC}$ $A2 \rightarrow V_{CC}$ $A3 \rightarrow O$ $A4 \rightarrow O$ $A7 \rightarrow O$ $A7 \rightarrow O$ $A12 \rightarrow O$ $A12 \rightarrow O$ $A12 \rightarrow O$ $A12 \rightarrow O$ $A13 \rightarrow O$ $A12 \rightarrow O$ $A12 \rightarrow O$ $A13 \rightarrow O$ $A12 \rightarrow O$ A12



Pin arrangement for SOJ

and TSOP 2



Bottom View 48BGA

Selection guide

WE

 \overline{UB} \overline{OE}

LB-

CF

| | | -10 | -12 | -15 | -20 | Unit |
|-----------------------------------|------------|-----|-----|-----|-----|------|
| Maximum address access time | | 10 | 12 | 15 | 20 | ns |
| Maximum output enable access time | | 4 | 5 | 6 | 7 | ns |
| Maximum operating current | Industrial | 180 | 160 | 140 | 110 | mA |
| | Commercial | 170 | 150 | 130 | 100 | mA |
| Maximum CMOS standby current | | 8 | 8 | 8 | 8 | mA |

Functional description

The AS7C34098A is a high-performance CMOS 4,194,304-bit Static Random Access Memory (SRAM) device organized as 262,144 words \times 16 bits. It is designed for memory applications where fast data access, low power, and simple interfacing are desired.

Equal address access and cycle times (t_{AA} , t_{RC} , t_{WC}) of 10/12/15/20 ns with output enable access times (t_{OE}) of 4/5/6/7 ns are ideal for high-performance applications. The chip enable input \overline{CE} permits easy memory expansion with multiple-bank memory systems.

When \overline{CE} is high the device enters standby mode. The device is guaranteed not to exceed 28.8mW power consumption in CMOS standby mode. A write cycle is accomplished by asserting write enable (\overline{WE}) and chip enable (\overline{CE}). Data on the input pins I/O1–I/O16 is written on the rising edge of \overline{WE} (write cycle 1) or \overline{CE} (write cycle 2). To avoid bus contention, external devices should drive I/O pins only after outputs have been disabled with output enable (\overline{OE}) or write enable (\overline{WE}).

A read cycle is accomplished by asserting output enable (\overline{OE}) and chip enable (\overline{CE}), with write enable (\overline{WE}) high. The chip drives I/O pins with the data word referenced by the input address. When either chip enable or output enable is inactive, or write enable is active, output drivers stay in high-impedance mode.

The device provides multiple center power and ground pins, and separate byte enable controls, allowing individual bytes to be written and read. \overline{LB} controls the lower bits, I/O1–I/O8, and \overline{UB} controls the higher bits, I/O9–I/O16.

All chip inputs and outputs are TTL- and CMOS-compatible, and operation is for 3.3V (AS7C34098A) supply. The device is available in the JEDEC standard 400-mil, 44-pin SOJ, TSOP 2.

| Parameter | Symbol | Min | Max | Unit |
|--|-------------------|-------|-----------------------|------|
| Voltage on V _{CC} relative to GND | V _{t1} | -0.50 | +5.0 | V |
| Voltage on any pin relative to GND | V _{t2} | -0.50 | V _{CC} +0.50 | V |
| Power dissipation | P _D | - | 1.5 | W |
| Storage temperature (plastic) | T _{stg} | -65 | +150 | °C |
| Ambient temperature with V_{CC} applied | T _{bias} | -55 | +125 | °C |
| DC current into outputs (low) | I _{OUT} | _ | ±20 | mA |

Absolute maximum ratings

Note: Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

| T | | 401 | 61 | |
|----|-----|-----|----|----|
| 11 | uth | ιa | D. | te |
| | | | | |

| CE | WE | OE | LB | UB | I/O1–I/O8 | I/O9–I/O16 | Mode |
|----|----|----|----|----|------------------|------------------|-----------------------------------|
| Н | Х | Х | Х | Х | High Z | High Z | Standby (I_{SB}, I_{SB1}) |
| L | Н | Н | Х | Х | Histo 7 | III. h 7 | Output disable (I _{CC}) |
| L | Х | Х | Н | Н | High Z | High Z | Output disable (I _{CC}) |
| | | | L | Н | D _{OUT} | High Z | |
| L | Н | L | Н | L | High Z | D _{OUT} | Read (I _{CC}) |
| | | | L | L | D _{OUT} | D _{OUT} | |
| | | | L | Н | D _{IN} | High Z | |
| L | L | Х | Н | L | High Z | D _{IN} | |
| | | | L | L | D _{IN} | D _{IN} | Write (I _{CC}) |

Key: X = Don't care, L = Low, H = High.



Recommended operating conditions

| Parameter | Parameter | | Min | Typical | Max | Unit |
|-------------------------------|----------------|-------------------|------|---------|----------------|------|
| Supply voltage | Supply voltage | | | 3.3 | 3.6 | V |
| Input voltage | Input voltage | | | _ | $V_{CC} + 0.5$ | V |
| input voltage | | V _{IL} * | -0.5 | _ | 0.8 | V |
| Ambient operating temperature | commercial | T _A | 0 | _ | 70 | °C |
| Amolent operating temperature | industrial | T _A | -40 | - | 85 | °C |

 $\label{eq:VIL} \begin{array}{l} * \\ * \\ V_{IL} \\ max = V_{CC} \\ + \\ 2.0V \\ \mbox{for pulse width less than 5ns.} \end{array}$

DC operating characteristics (over the operating range)¹

| | | | | -] | 10 | _ | 12 | -15 | | -20 | | |
|---------------------------------|------------------|---|------------|-----|-----|-----|-----|-----|-----|-----|-----|------|
| Parameter | Symbol | Test conditions | | Min | Max | Min | Max | Min | Max | Min | Max | Unit |
| Input leakage current | I _{LI} | V _{CC} = Max V _{IN} = GND to V _C | CC | _ | 1 | _ | 1 | _ | 1 | _ | 1 | μA |
| Output leakage current | I _{LO} | $\frac{V_{CC} = Max}{CE = V_{IH} \text{ or } OE = V_{IH}}$ or $\overline{WE} = V_{IL}$ $V_{I/O} = GND \text{ to } V_{CC}$ | | _ | 1 | _ | 1 | _ | 1 | _ | 1 | μA |
| Operating | T | V _{CC} = Max | Industrial | _ | 180 | - | 160 | — | 140 | - | 110 | mA |
| power supply current | I _{CC} | $\overline{\text{CE}} \le \text{V}_{\text{IL}}, \text{ f} = \text{f}_{\text{max}} \text{I}_{\text{OUT}} = 0 \text{mA}$ | Commercial | - | 170 | - | 150 | - | 130 | - | 100 | mA |
| Stor dhe sources | I _{SB} | $\frac{V_{CC} = Max}{\overline{CE} \ge V_{IH}, f = Ma}$ | IX | _ | 60 | _ | 60 | _ | 60 | _ | 60 | mA |
| Standby power supply current | I _{SB1} | $\label{eq:VCC} \begin{split} V_{CC} &= Max\\ \overline{CE} \geq V_{CC} - 0.2V, \ V_{IN} \geq V_{CC} - 0.2V \ or\\ V_{IN} \leq 0.2V, \ f = 0 \end{split}$ | | _ | 8 | _ | 8 | _ | 8 | _ | 8 | mA |
| Output voltage | V _{OL} | $I_{OL} = 8 \text{ mA}, V_{CC} = Min$ | | — | 0.4 | — | 0.4 | — | 0.4 | Ι | 0.4 | V |
| Sulput totage | V _{OH} | $I_{OH} = -4 \text{ mA}, V_{CC} =$ | Min | 2.4 | - | 2.4 | — | 2.4 | - | 2.4 | - | V |

Capacitance (f = 1MHz, $T_a = 25^{\circ} \text{ C}, V_{CC} = \text{NOMINAL})^2$

| Parameter | Symbol | Signals | Test conditions | Max | Unit |
|-------------------|------------------|-----------------------|-------------------------|-----|------|
| Input capacitance | C _{IN} | A, CE, WE, OE, UB, LB | $V_{IN} = 0V$ | 6 | pF |
| I/O capacitance | C _{I/O} | I/O | $V_{IN} = V_{OUT} = 0V$ | 8 | pF |

@_

Read cycle (over the operating range)^{3,9}

| | | -1 | 10 | -1 | 12 | -1 | 15 | -2 | 20 | | |
|--|------------------|-----|-----|-----|-----|-----|-----|-----|-----|------|-------|
| Parameter | Symbol | Min | Max | Min | Max | Min | Max | Min | Max | Unit | Notes |
| Read cycle time | t _{RC} | 10 | - | 12 | - | 15 | - | 20 | - | ns | |
| Address access time | t _{AA} | - | 10 | _ | 12 | _ | 15 | _ | 20 | ns | |
| Chip enable (\overline{CE}) access time | t _{ACE} | - | 10 | _ | 12 | _ | 15 | - | 20 | ns | |
| Output enable (\overline{OE}) access time | t _{OE} | - | 4 | _ | 5 | _ | 6 | _ | 7 | ns | |
| Output hold from address change | t _{OH} | 3 | _ | 3 | _ | 3 | _ | 3 | _ | ns | 5 |
| $\overline{\operatorname{CE}}$ Low to output in low Z | t _{CLZ} | 3 | - | 3 | - | 3 | _ | 3 | _ | ns | 4, 5 |
| $\overline{\text{CE}}$ High to output in high Z | t _{CHZ} | _ | 5 | _ | 6 | _ | 7 | _ | 9 | ns | 4, 5 |
| OE Low to output in low Z | t _{OLZ} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | 4, 5 |
| $\overline{\text{OE}}$ High to output in high Z | t _{OHZ} | - | 5 | _ | 6 | _ | 7 | _ | 9 | ns | 4, 5 |
| $\overline{\text{LB}}, \overline{\text{UB}}$ access time | t _{BA} | - | 5 | _ | 6 | _ | 7 | _ | 8 | ns | |
| $\overline{\text{LB}}$, $\overline{\text{UB}}$ Low to output in low Z | t _{BLZ} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | |
| $\overline{\text{LB}}, \overline{\text{UB}}$ High to output in high Z | t _{BHZ} | _ | 5 | _ | 6 | _ | 7 | - | 9 | ns | |
| Power up time | t _{PU} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | 5 |
| Power down time | t _{PD} | - | 10 | — | 12 | - | 15 | | 20 | ns | 5 |

Key to switching waveforms

Rising input

Falling input

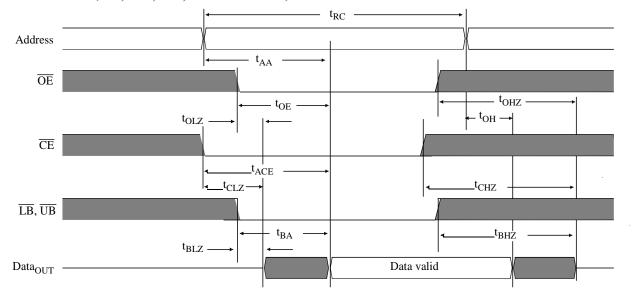
Undefined/don't care

Read waveform 1 (address controlled)^{6,7,9}

| | | t | RC | |
|---------------------|--------------------------|-------------------------|------------|----------------------|
| Address | | | | |
| | $t_{OH} \longrightarrow$ | $\xrightarrow{t_{AA}} $ | | ι←−− t _{OH} |
| Data _{OUT} | Previous data valid | | Data valid | |



Read waveform 2 (\overline{CE} , \overline{OE} , \overline{UB} , \overline{LB} controlled)^{6,8,9}



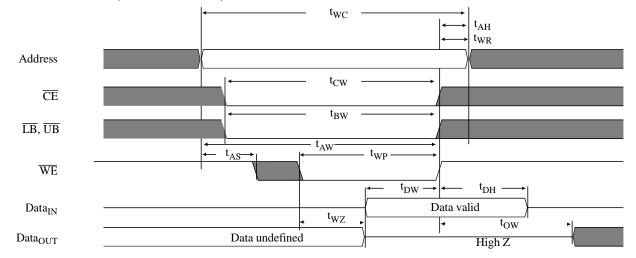
Write cycle (over the operating range)¹⁰

| | | _ | 10 | _ | 12 | _ | 15 | _ | 20 | | |
|--|------------------|-----|-----|-----|-----|-----|-----|-----|-----|------|------|
| Parameter | Symbol | Min | Max | Min | Max | Min | Max | Min | Max | Unit | Note |
| Write cycle time | t _{WC} | 10 | - | 12 | _ | 15 | _ | 20 | _ | ns | |
| Chip enable $\overline{(CE)}$ to write end | t _{CW} | 7 | _ | 8 | _ | 10 | _ | 12 | _ | ns | |
| Address setup to write end | t _{AW} | 7 | _ | 8 | _ | 10 | _ | 12 | _ | ns | |
| Address setup time | t _{AS} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | |
| Write pulse width ($\overline{OE} = High$) | t _{WP1} | 7 | _ | 8 | _ | 10 | _ | 12 | _ | ns | |
| Write pulse width ($\overline{OE} = Low$) | t _{WP2} | 10 | _ | 12 | _ | 15 | _ | 20 | _ | ns | |
| Write recovery time | t _{WR} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | |
| Address hold from end of write | t _{AH} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | |
| Data valid to write end | t _{DW} | 5 | _ | 6 | | 7 | | 9 | | ns | |
| Data hold time | t _{DH} | 0 | _ | 0 | _ | 0 | _ | 0 | _ | ns | 4, 5 |
| Write enable to output in High-Z | t _{WZ} | 0 | 5 | 0 | 6 | 0 | 7 | 0 | 9 | ns | 4, 5 |
| Output active from write end | t _{OW} | 3 | - | 3 | - | 3 | - | 3 | - | ns | 4, 5 |
| Byte enable Low to write end | t _{BW} | 7 | _ | 8 | _ | 10 | _ | 12 | _ | ns | 4, 5 |

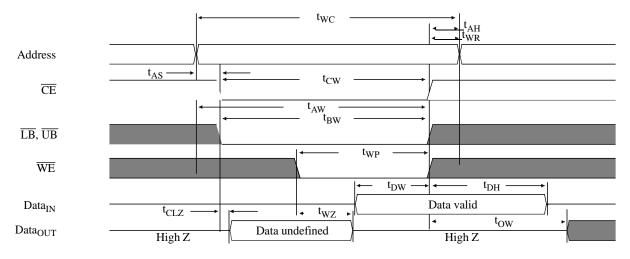
AS7C34098A



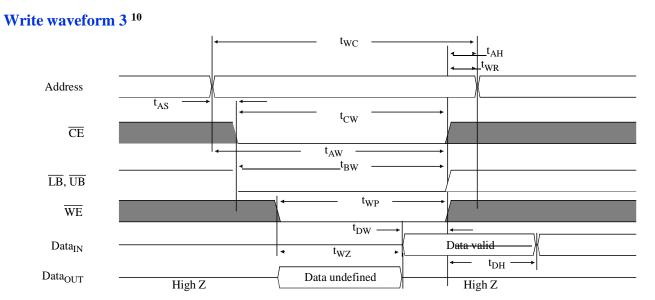
Write waveform $1(\overline{WE} \text{ controlled})^{10}$



Write waveform 2 (CE controlled)¹⁰

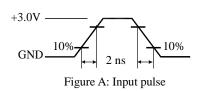


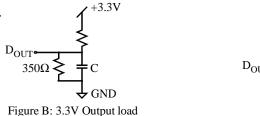




AC test conditions

- Output load: see Figure B.
- Input pulse level: GND to 3.0V. See Figure A.
- Input rise and fall times: 2 ns. See Figure A.
- Input and output timing reference levels: 1.5V.



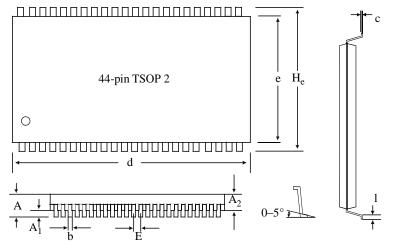




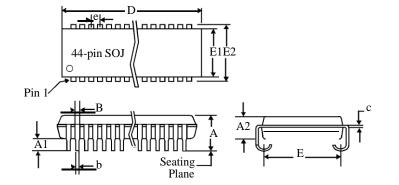
Notes

- 1 During V_{CC} power-up, a pull-up resistor to V_{CC} on \overline{CE} is required to meet I_{SB} specification.
- 2 This parameter is sampled, but not 100% tested.
- 3 For test conditions, see AC Test Conditions, Figures A and B.
- 4 t_{CLZ} and t_{CHZ} are specified with $C_L = 5pF$ as in Figure B. Transition is measured $\pm 500mV$ from steady-state voltage.
- 5 This parameter is guaranteed, but not tested.
- $\overline{\text{WE}}$ is High for read cycle.
- 7 $\overline{\text{CE}}$ and $\overline{\text{OE}}$ are Low for read cycle.
- 8 Address valid prior to or coincident with $\overline{\text{CE}}$ transition Low.
- 9 All read cycle timings are referenced from the last valid address to the first transitioning address.
- 10 All write cycle timings are referenced from the last valid address to the first transitioning address.
- 11 C=30pF, except on High Z and Low Z parameters, where C=5pF.

Package dimensions



| | 44-pin ' | TSOP 2 |
|-----------------------|-----------------|----------|
| | Min (mm) | Max (mm) |
| A | | 1.2 |
| A ₁ | 0.05 | 0.15 |
| A ₂ | 0.95 | 1.05 |
| b | 0.3 | 0.45 |
| С | 0.12 | 0.21 |
| d | 18.31 | 18.52 |
| е | 10.06 | 10.26 |
| H _e | 11.68 | 11.94 |
| E | 0.80 (t | ypical) |
| l | 0.40 | 0.60 |

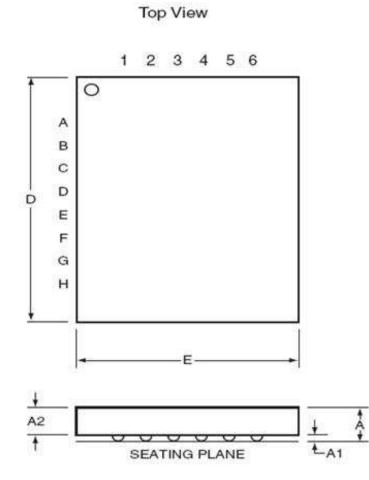


| | 44-pin SO | J 400 mils |
|-----------|-----------|------------|
| | Min(mils) | Max(mils) |
| Α | 0.128 | 0.148 |
| A1 | 0.025 | - |
| A2 | 0.105 | 0.115 |
| B | 0.026 | 0.032 |
| b | 0.015 | 0.020 |
| С | 0.007 | 0.013 |
| D | 1.120 | 1.130 |
| E | 0.370 | NOM |
| E1 | 0.395 | 0.405 |
| E2 | 0.435 | 0.445 |
| e | 0.050 | NOM |

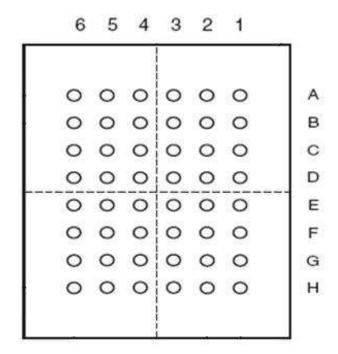
AS7C34098A



Outline of 48BGA



Bottom View





1. Controlling dimensions are in millimeters.



| | MILLIMETERS | | | | |
|------|-------------|--------------|-------|--|--|
| Sym. | Min. | Тур. | Max. | | |
| A | 332 | <u></u> | 1.20 | | |
| A1 | 0.24 | <u>2-3</u> 1 | 0.30 | | |
| A2 | 0.60 | | 94-23 | | |
| D | 9.90 | 10.00 | 10.10 | | |
| D1 | 5.25 BSC | | | | |
| E | 7.90 | 8.00 | 8.10 | | |
| E1 | 3 | .75 BS | С | | |
| е | 0 | .75 BS | С | | |
| b | 0.30 | 0.35 | 0.40 | | |



Ordering Codes

| Package | Temperature | 10 ns | 12 | 15 ns | 20 ns |
|---------|-------------|------------------|-----------------|-----------------|-----------------|
| SOJ | Commercial | AS7C34098A-10JC | AS7C34098A-12JC | AS7C34098A-15JC | AS7C34098A-20JC |
| | Industrial | AS7C34098A-10JI | AS7C34098A-12JI | AS7C34098A-15JI | AS7C34098A-20JI |
| BGA | Industrial | AS7C34098A-10BIN | | | |
| TSOP 2 | Commercial | AS7C34098A-10TC | AS7C34098A-12TC | AS7C34098A-15TC | AS7C34098A-20TC |
| | Industrial | AS7C34098A-10TI | AS7C34098A-12TI | AS7C34098A-15TI | AS7C34098A-20TI |

Note: Add suffix 'N' to the above part numbers for Lead Free Parts. (EX: AS7C34098A - 10TCN)

Part numbering system

| AS7C | X | 4098A | -XX | J / T or B | X | X |
|-------------|---------------------------|------------------|----------------|--|---|---|
| SRAM prefix | Voltage: 3 - 3.3V CMOS | Device number | Access time | Packages: J: SOJ 400 mil T: TSOP 2 B: BGA | Temperature ranges: C: Commercial, 0°C to 70°C I: Industrial, –40°C to 85°C | |



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